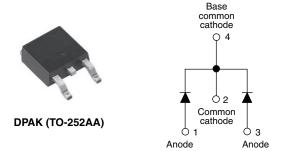


Ultrafast Rectifier, 2 x 3 A FRED Pt®



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 3 A				
V_{R}	200 V				
V _F at I _F	0.9 V				
t _{rr} typ.	See Recovery table				
T _J max.	175 °C				
Package	DPAK (TO-252AA)				
Circuit configuration	Common cathode				

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT HALOGEN

DESCRIPTION / APPLICATIONS

VS-MURD620CTHM3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	V _{RRM}		200	V			
Average rectified forward current per device	I _{F(AV)}	Total device, rated V _R , T _C = 146 °C	6				
Non-repetitive peak surge current	I _{FSM}		50	Α			
Peak repetitive forward current per diode	I _{FM}	Rated V _R , square wave, 20 kHz, T _C = 146 °C	6				
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

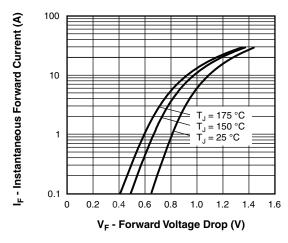
ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-		
	V _F	I _F = 3 A	-	0.9	1.0	.,	
Forward voltage		I _F = 3 A, T _J = 125 °C	-	0.78	0.96	V	
Torward voltage		I _F = 6 A	-	1	1.2		
		I _F = 6 A, T _J = 125 °C	-	0.89	1.13		
Povorco logizado gurront	erse leakage current I _R	$V_R = V_R$ rated	-	-	5	μA	
Reverse leakage current		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	250	μΑ	
Junction capacitance	C _T	V _R = 200 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nΗ	





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 A, dI_F/dt =$	50 A/μs, V _R = 30 V	ı	20	35		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 3 A dI _F /dt = 200 A/μs V _R = 160 V	-	19	-	ns A	
		T _J = 125 °C		-	26	-		
Dook room ourrent	I _{RRM}	T _J = 25 °C		-	3.1	-		
Peak recovery current		T _J = 125 °C		-	4.6	-		
Reverse recovery charge	0	T _J = 25 °C		-	30	-	nC	
	Q_{rr}	T _J = 125 °C		-	60	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case per leg	R _{thJC}		-	-	9.0		
Thermal resistance, junction to ambient per leg	R _{thJA}		-	-	80	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	-	-		
Maight			-	0.3	-	g	
Weight			-	0.01	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style DPAK (TO-252AA)		MURD	520CTH	•	





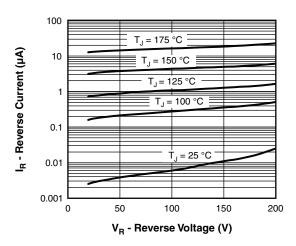


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

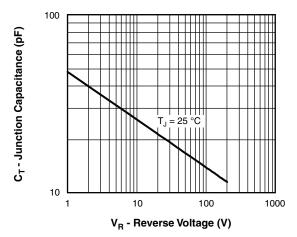


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

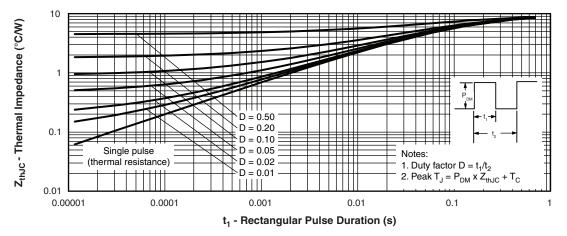


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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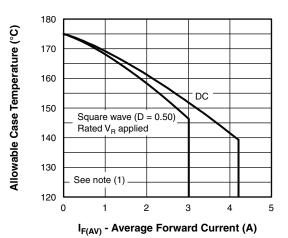


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

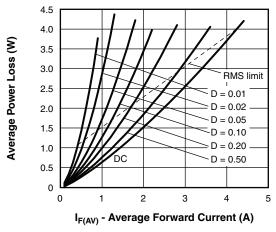


Fig. 6 - Forward Power Loss Characteristics



 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

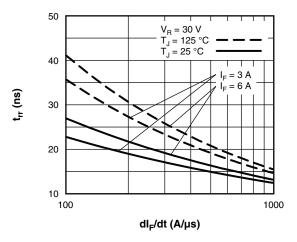


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

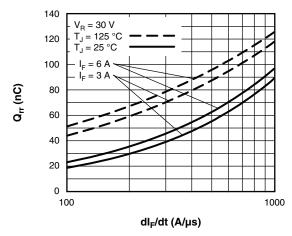


Fig. 8 - Typical Stored Charge vs. dl_E/dt

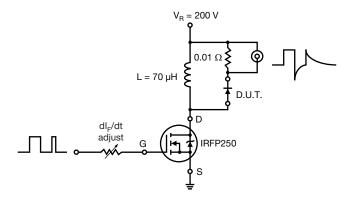
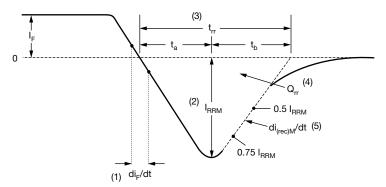


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{r}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and $\mathbf{I}_{\mathrm{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

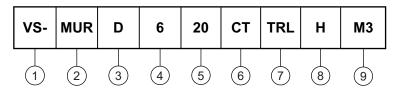
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Ultrafast MUR series

3 - D = DPAK

- Current rating (6 = 6 A)

5 - Voltage rating (20 = 200 V)

- CT = center tap (dual) TR = tape and reel

7 - Tape and reel suffix — TRL = tape and reel (left oriented)
TRR = tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-MURD620CTHM3	75	Antistatic plastic tube				
VS-MURD620CTTRHM3	2000	13" diameter reel				
VS-MURD620CTTRLHM3	3000	13" diameter reel				
VS-MURD620CTTRRHM3	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95519			
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



DPAK (TO-252AA)



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	1	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	4.93	-	0.194	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL MILLIMETERS INCHI		HES	NOTES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29 BSC 0.090 BSC				
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108	REF.	
L2	0.51	0.51 BSC		BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
	•	•		•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (5) Outline conforms to JEDEC® outline TO-252AA, except for D1 dimension



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Vishay

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